

# PJL9812

## 30V Dual N-Channel Enhancement Mode MOSFET

<b>Voltage</b>	<b>30 V</b>	<b>Current</b>	<b>6 A</b>
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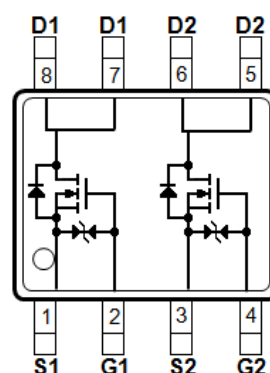
### Features

- $R_{DS(ON)}$  ,  $V_{GS}@10V$ ,  $I_D@6A<35m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS}@4.5V$ ,  $I_D@4A<40m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS}@2.5V$ ,  $I_D@2A<54m\Omega$
- Advanced Trench Process Technology
- ESD Protected 2KV HBM
- High density cell design for ultra low on-resistance
- Green molding compound as per IEC61249 Std.  
(Halogen Free)

### Mechanical Data

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams
- Marking: L9812

SOP-8



## Maximum Ratings and Thermal Characteristics ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	30	V
Gate-Source Voltage		V <sub>GS</sub>	±12	V
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	6	A
	T <sub>A</sub> =70°C		4.8	
Pulsed Drain Current <sup>(Note 1)</sup>		I <sub>DM</sub>	24	A
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2	W
	T <sub>A</sub> =70°C		1.3	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance		R <sub>θJA</sub>	62.5	°C/W
- Junction to Ambient, t≤10s <sup>(Note 5)</sup>				



# PJL9812

## Electrical Characteristics ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.5	0.8	1.3	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =6.0A	-	30	35	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.0A	-	33	40	
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =2.0A	-	41	54	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V	-	-	±10	uA
Dynamic <sup>(Note 6)</sup>						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =15V, I <sub>D</sub> =6.0A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	5.1	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.8	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	1.4	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=200KHZ	-	421	-	pF
Output Capacitance	C <sub>oss</sub>		-	43	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	35	-	
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DD</sub> =15V, I <sub>D</sub> =1.0A, V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω <sup>(Note 1,2)</sup>	-	3.3	-	ns
Turn-On Rise Time	tr		-	24	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	19	-	
Turn-Off Fall Time	tf		-	16	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>s</sub>	---	-	-	6	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =6.0A, V <sub>GS</sub> =0V	-	0.86	1.2	V

### NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. Repetitive rating, pulse width limited by junction temperature  $T_J(MAX)=150^{\circ}\text{C}$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^{\circ}\text{C}$ .
5.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.

# PJL9812

## TYPICAL CHARACTERISTIC CURVES

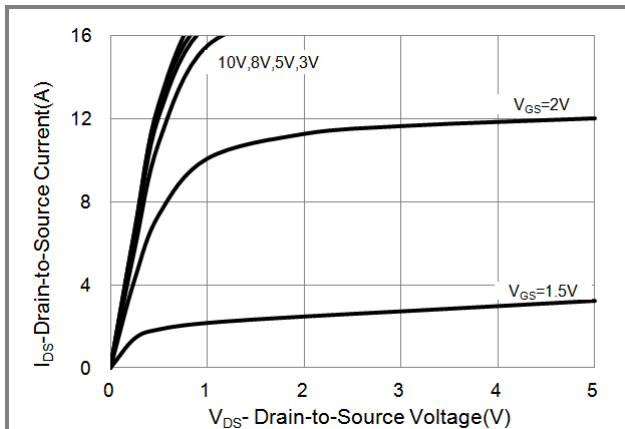


Fig.1 On-Region Characteristics

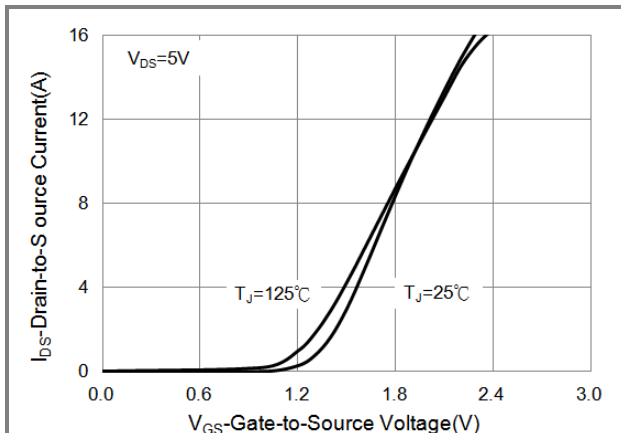


Fig.2 Transfer Characteristics

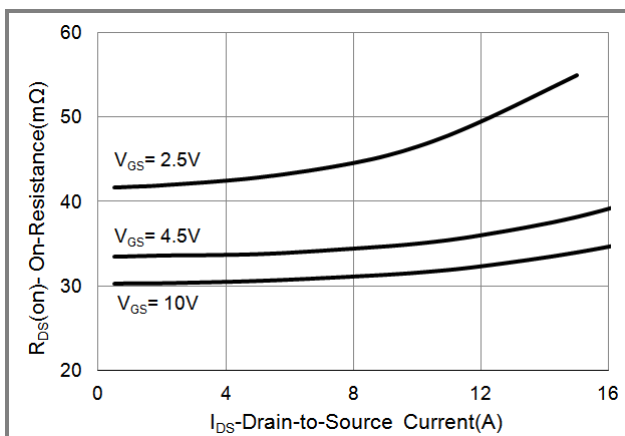


Fig.3 On-Resistance vs. Drain Current

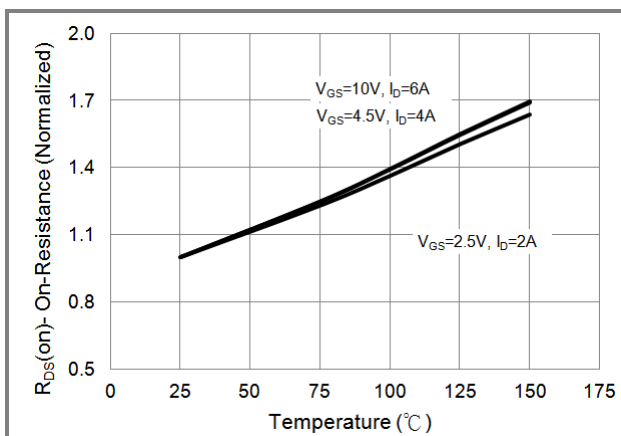


Fig.4 On-Resistance vs. Junction temperature

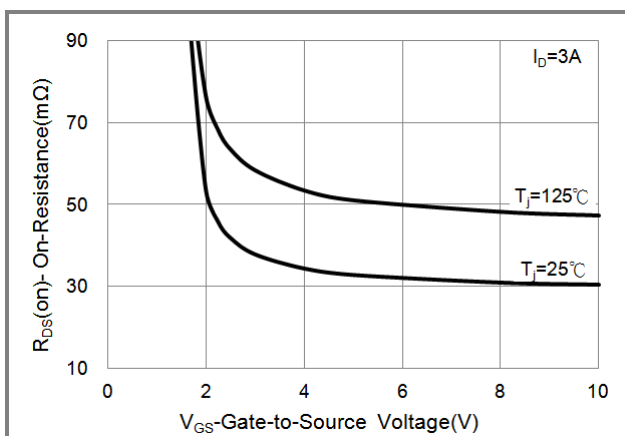


Fig.5 On-Resistance Variation with VGS.

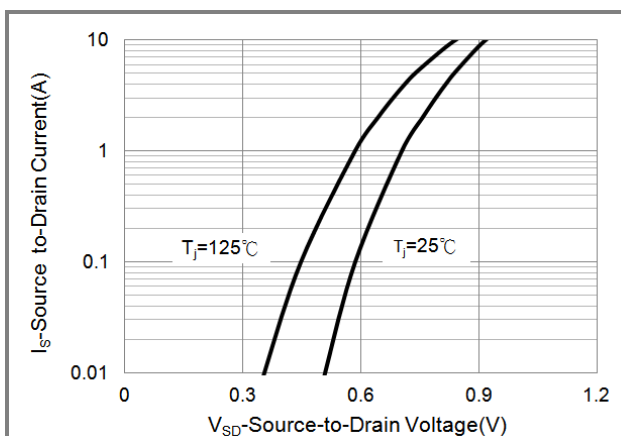


Fig.6 Body Diode Characteristics

# PJL9812

## TYPICAL CHARACTERISTIC CURVES

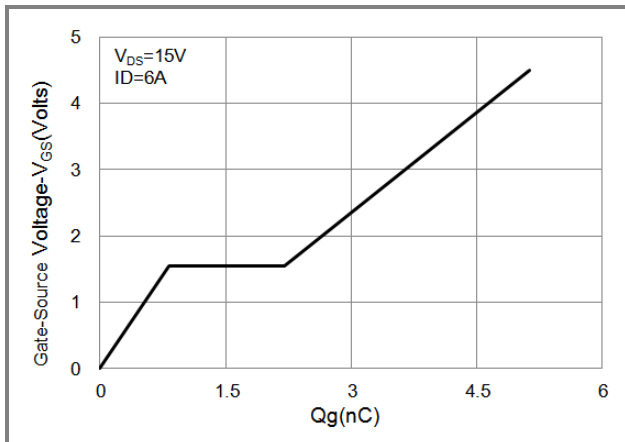


Fig.7 Gate-Charge Characteristics

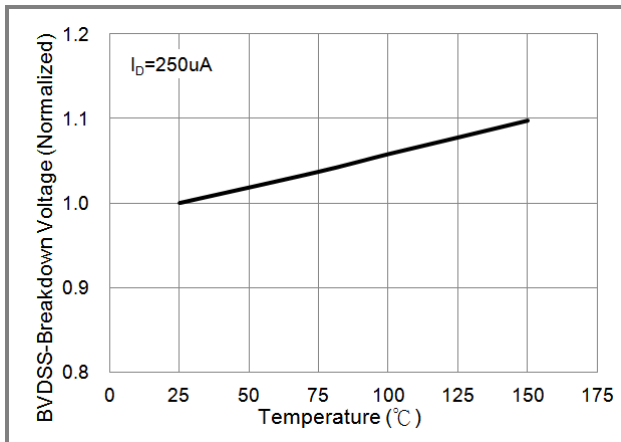


Fig.8 Breakdown Voltage Variation vs. Temperature

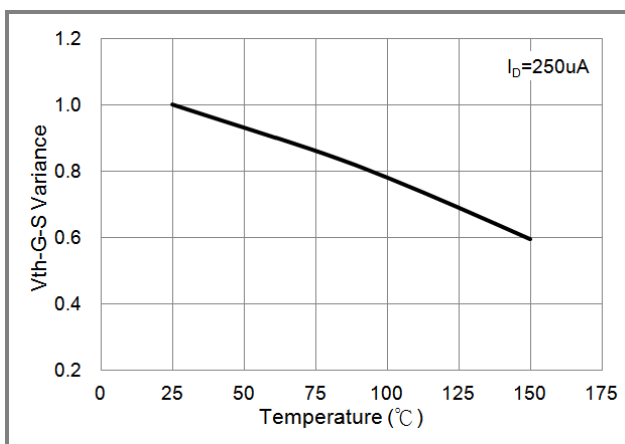


Fig.9 Threshold Voltage Variation with Temperature.

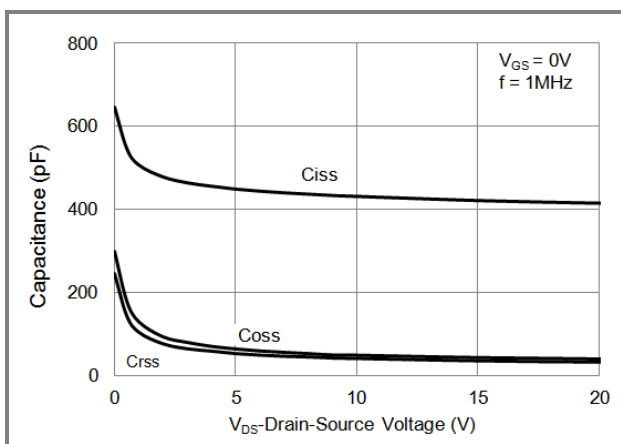


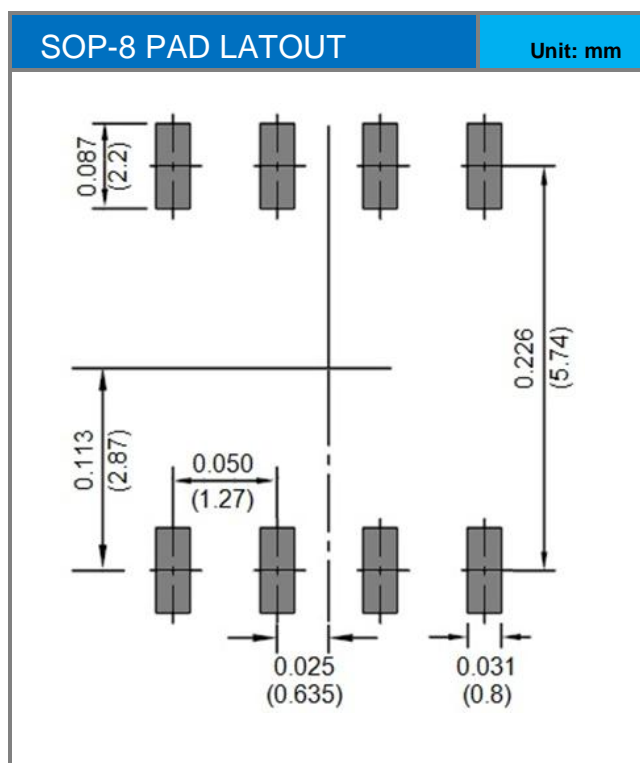
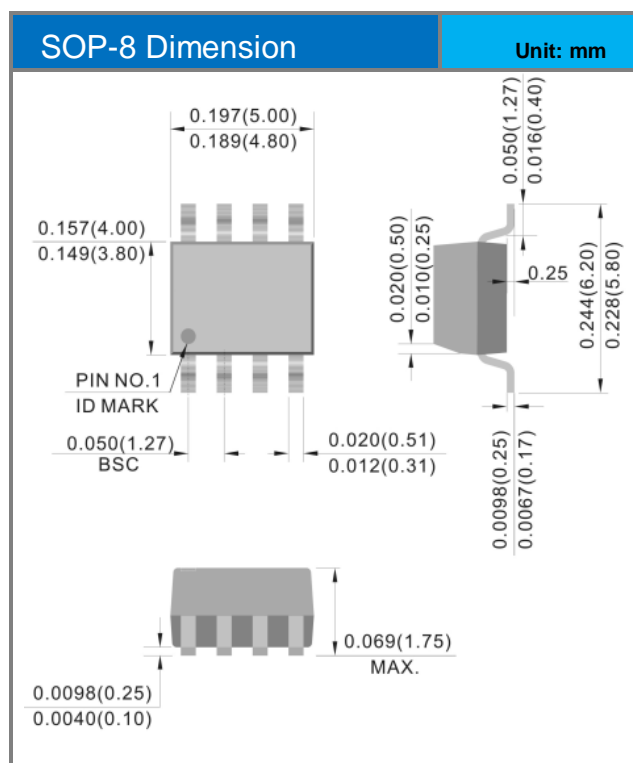
Fig.10 Capacitance vs. Drain-Source Voltage.

# PJL9812

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9812_R2_00001	SOP-8	2.5K pcs / 13" reel	L9812	Halogen free

## Packaging Information & Mounting Pad Layout





## **PJL9812**

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